

Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain-to-Source Voltage		60	V	
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V	
I <sub>D</sub>	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	50	Α	
	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4		
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	19	mJ	
P <sub>D</sub>	Power Dissipation		75	W	
	Derate Above 25°C		0.5	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.0	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W	

Notes:

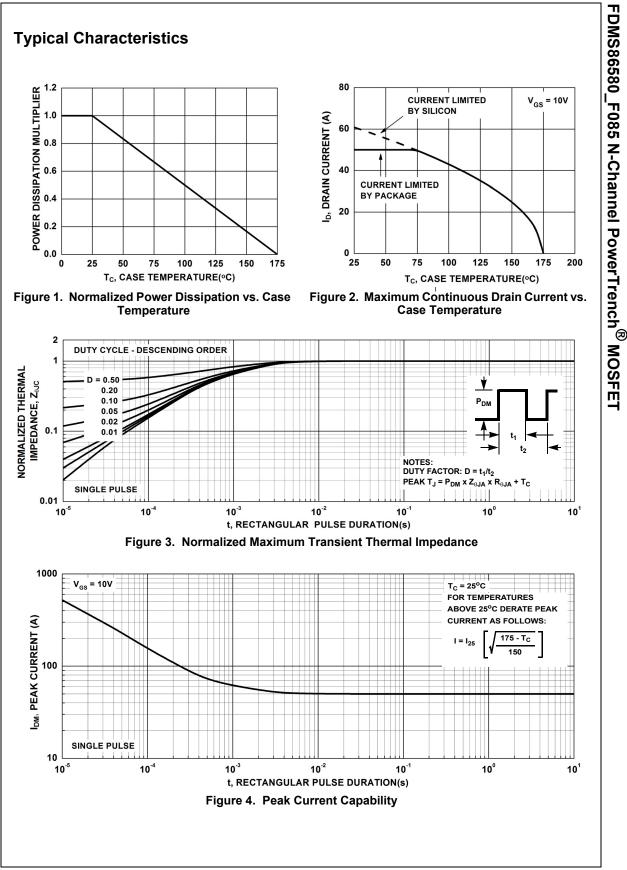
1: Current is limited by bondwire configuration.

2: Starting T<sub>J</sub> = 25°C, L = 20µH, I<sub>AS</sub> = 44A, V<sub>DD</sub> = 60V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche. 3:  $R_{0JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design, while R<sub>0JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

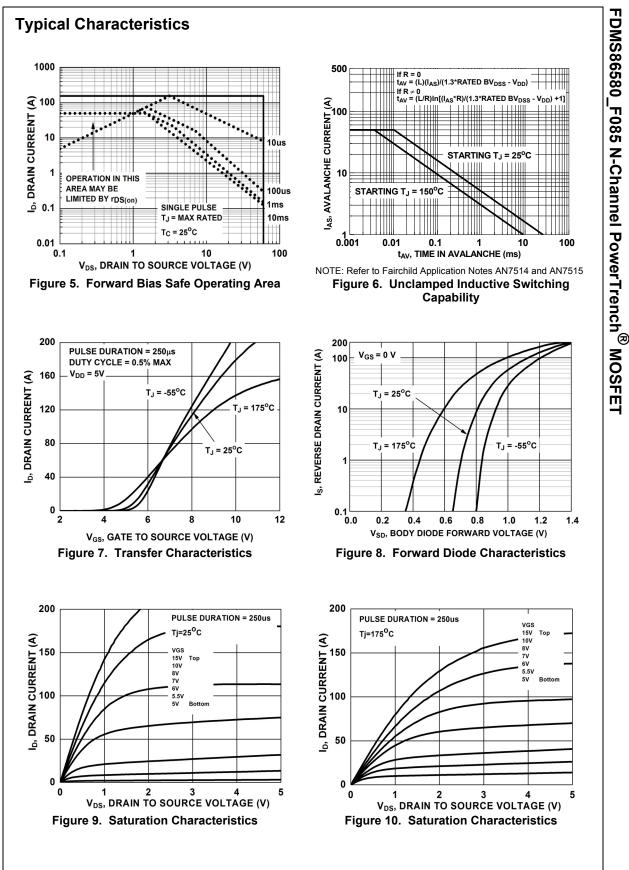
# Package Marking and Ordering Information

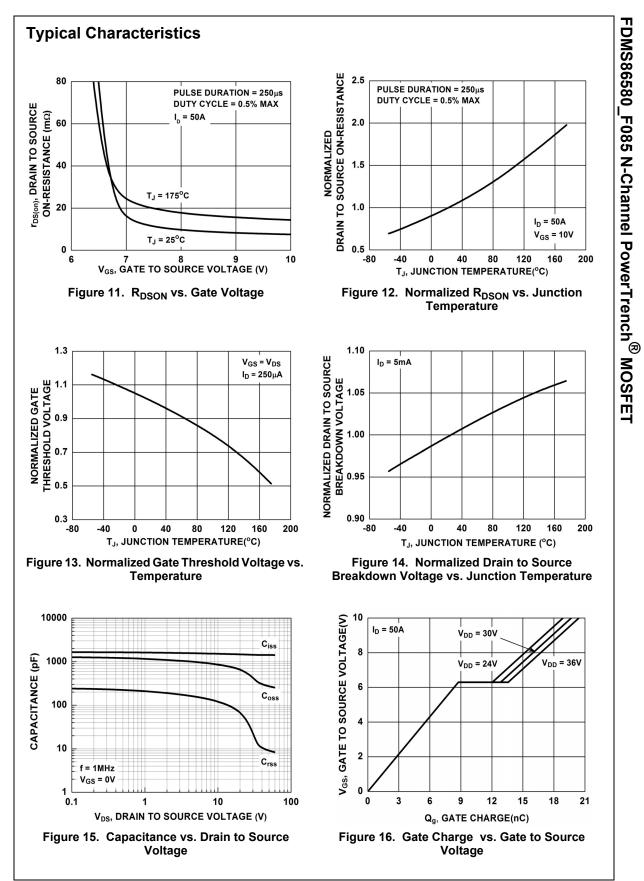
Device Marking	Device	Package	Reel Size	Tape Width	Quantity		
FDMS86580	FDMS86580_F085	Power 56	13"	12mm	3000units		

Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	racteristics				1		L	
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA,	$V_{CS} = 0V$		60	-	-	V
VD33	Drain-to-Source Leakage Current	$V_{\rm DS} = 60V$ , $T_{\rm J} = 25^{\circ}C$		-	-	1	μA	
I <sub>DSS</sub>		$V_{GS} = 0V$			-	-	1	mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
On Cha	racteristics				_			
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> ,	I <sub>D</sub> = 250μ/	4	2.0	3.5	4.2	V
	<b>_</b>		-		-	7.9	9.6	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V			-	15.6	19.5	mΩ
C <sub>iss</sub>	Input Capacitance			-	1430	-	рF	
C <sub>oss</sub>	Output Capacitance	$v_{\rm DS} = 30V, v_{\rm GS} = 0V,$ - f = 1MHz			-	440	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				-	25	-	pF
R <sub>g</sub>	Gate Resistance	V <sub>GS</sub> = 0.5V,			-	1.8	-	Ω
ጋ <sub>g(ToT)</sub>	Total Gate Charge	V <sub>GS</sub> = 0 to 1	v	<sub>DD</sub> = 30V	-	20	30	nC
၃ <sub>g(th)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2		) = 50A	-	3	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge				-	9	-	nC
Q <sub>gd</sub>	Gate-to-Drain "Miller" Charge				-	4	-	nC
Switchi	ng Characteristics							
on	Turn-On Time				-	-	30	ns
d(on)	Turn-On Delay				-	13	-	ns
r	Rise Time	$V_{DD}$ = 30V, I <sub>D</sub> = 50A, $V_{GS}$ = 10V, R <sub>GEN</sub> = 6 $\Omega$		-	7	-	ns	
d(off)	Turn-Off Delay			-	15	-	ns	
f	Fall Time			-	5	-	ns	
t <sub>off</sub>	Turn-Off Time				-	-	30	ns
)rain-S	ource Diode Characteristics							
V <sub>SD</sub>	Source-to-Drain Diode Voltage		I <sub>SD</sub> = 50A, V <sub>GS</sub> = 0V		-	0.97	1.3	V
▼ SD	Source-to-brain bloce voltage	$I_{SD} = 25A, V_{GS} = 0V$			-	0.88	1.2	V
t <sub>rr</sub>	Reverse-Recovery Time	$V_{DD}$ = 48V, I <sub>F</sub> = 50A, dI <sub>SD</sub> /dt = 100A/µs		-	44	66	ns	
Q <sub>rr</sub>	Reverse-Recovery Charge			-	28	42	nC	



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